<https://doi.org/10.1038/s41467-019-11927-x>

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Publisher Correction: Gallium arsenide solar cells grown at rates exceeding $300 \mu\text{m h}^{-1}$ by hydride vapor phase epitaxy

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Correction to: *Nature Communications* <https://doi.org/10.1038/s41467-019-11341-3>, published online 26 July 2019.

The original PDF version of this Article contained an error in Fig. 3, which was truncated to omit the two right-most data points in each panel. This has been corrected in the PDF version of the Article. The HTML version was correct from the time of publication.

Published online: 03 September 2019

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